Thermal contributions to the structural phase transitions of crystalline aluminum under ultrahigh pressures

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The rapid development of experimental techniques makes it possible to explore the phase behaviors of condensed matters under extreme conditions\textsuperscript{1,2} and simultaneously requests more thorough understandings from the perspective of theoretical physics. Although the quantum mechanics \textit{ab initio} simulations paved a promising way for researches of the properties from the atomic scale\textsuperscript{3}\textsuperscript{4} and progress has been achieved in predicting the structural stability by the global optimization algorithms\textsuperscript{5}\textsuperscript{11} that commonly adopt the criteria of potential energy or enthalpy obtained by electronic-structure computations within the Born-Oppenheimer approximation at $T=0$K, it remains a challenge to precisely describe the realistic scenarios at finite temperatures\textsuperscript{12}\textsuperscript{13}, in the cases of which the thermodynamic effects have to be taken into account due to nucleus vibrations\textsuperscript{14} and the free energy (FE) that incorporates additional kinetic energy and entropy is the very criterion to determine the equilibrium structural phase\textsuperscript{15}. Based on \textit{ab initio} computations, the phonon model within the quasi-harmonic approximation is widely used in order to include the thermal contributions to the FE\textsuperscript{14}\textsuperscript{20}, while the model would still produce unsatisfactory results of thermal expansion coefficient or conductivity\textsuperscript{21}\textsuperscript{24}.

The discrepancy between theoretical predictions and experimental measurements also exists in the pressure-induced structural phase transitions of the crystalline aluminum (Al), which serves as a benchmark system for high-pressure studies due to its simple \textit{sp} electron shells\textsuperscript{25}\textsuperscript{26}. In spite of the early experiments\textsuperscript{27}\textsuperscript{28} and \textit{ab initio} phonon computations\textsuperscript{29} reporting the FCC structure to be stable up to 1000 GPa at room temperature, theoretical works predicted a FCC$\rightarrow$HCP$\rightarrow$BCC phase transition within 600 GPa\textsuperscript{30}\textsuperscript{33}, which was observed by following experiments at around 220 (320) GPa\textsuperscript{34}\textsuperscript{38} or 198 (360) GPa\textsuperscript{39} for the FCC$\rightarrow$HCP (HCP$\rightarrow$BCC) respectively. Among the methods based on the criteria of enthalpy\textsuperscript{32}\textsuperscript{34} or pure phonon model\textsuperscript{30}\textsuperscript{31}, the most accurately predicted transition pressures so far were obtained on the basis of \textit{ab initio} phonon computations combined with semi-empirical SESAME equations of state (EOS)\textsuperscript{35}, as 185 and 389 GPa for the two transformations respectively, which largely improve the theoretical accuracy but still deviate about 15\% from the results in Ref.\textsuperscript{37} and about 7\% from the results in Ref.\textsuperscript{39}. In spite of the argument that the thermal effects may be negligible for many condensed-state systems at room temperature, a rough estimation in the previous studies\textsuperscript{30}\textsuperscript{33} indicated that a 90 GPa difference can be aroused by the lattice vibrations to the transition pressures, and therefore, the purpose of this letter is to introduce an alternative path to compute the phase behaviors of Al at room temperature in order to elaborate what impacts the thermal contributions are able to make on the system.

As formulated in statistical mechanics, the FE can be readily obtained without empirical parameters as long as the partition function (PF) is solved while the exact solution to the PF of condensed matters is a long-standing problem because of the complexity of the high dimensional configurational integral\textsuperscript{13}\textsuperscript{40}\textsuperscript{41}, so that state-of-the-art numerical algorithm for PF can hardly afford a system consisting of more than several hundred particles even using empirical interatomic force field and the determined transition pressures for Al were far from the experimental results\textsuperscript{42}. Very recently, we put forward...
a direct integral approach (DIA) to the PF of condensed state systems with ultrahigh efficiency and precision [43–46], and has been successfully applied to investigate the phase transitions of vanadium [47], the EOS of copper [43] and the optimum growth condition for 2-D materials [44] combined with density functional theory (DFT). Compared with quasi-harmonic phonon model, DIA was examined to be applicable to much wider realm with much higher precision [46]. As a result, DIA is applied to compute the PFs of FCC, HCP and BCC phases of crystalline Al, and the derived Gibbs FEs are used as the criterion to calculate the configurational integrals, because the effective lengths along the three axes, 

\[ L_x, L_y, L_z \]

are not equivalent to each other due to the asymmetric structure, as the same procedures applied to copper [43] and vanadium [47] in our previous works, Eq. (5) can be used to investigate the phase transitions of vanadium [47], the EOS of copper [43], and has been successfully applied to investigate the thermal contributions.

At first glance, the formalism of DIA may be argued to be similar to the phonon model with the assumption of (quasi)harmonic motions of atoms around their lattice site while neither the other two degrees of freedom of the atom nor all the other atoms are not allowed to move, and \( \mathcal{L} \) is call the effective length. The usage of Eqs. (5) and (6) depends on the geometric symmetry of the investigated structures. For the FCC and BCC structures, as the same procedures applied to copper [43] and vanadium [47] in our previous works, Eq. (5) can be used to calculate the configurational integrals, because the effective lengths along the three axes, \( \mathcal{L}_{x,y,z} \), of any atom in the conventional cubic supercell of FCC or BCC are apparently the same, while, in terms of the HCP structure, it is obvious that the three effective lengths, \( \mathcal{L}_{x,y,z} \), are not equivalent to each other due to the asymmetric geometry along the three axes, and thus, Eq. (6) should be used for the corresponding configurational integral.

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parameters, lattice symmetry, strength of interatomic interactions, and ultimately determines the harmonic or anharmonic attributions of atom motions at given temperatures. In other words, the thermal contributions from both the harmonic and anharmonic motions of the studied system are naturally included in the computations of DIA and our previous simulations have proved the accuracy of DIA over the model of quasiharmonic approximation.\(^\text{14}\)

As shown in Fig.1(b), the FCC and BCC structures of crystalline Al, for the sake of less computational cost, are represented in a \(3 \times 3 \times 3\) one-atom rhombohedral supercell where the basis vectors are set as

- \(\mathbf{a}_1 = a_{\text{rh}} \cdot (1, 0, 0)\),
- \(\mathbf{a}_2 = a_{\text{rh}} \cdot (\cos \alpha, \sin \alpha, 0)\),
- \(\mathbf{a}_3 = a_{\text{rh}} \cdot (\cos \alpha, -\cos \alpha, \sqrt{1 - 3 \cos^2 \alpha})\)

with \(a_{\text{rh}}\) denoting the lattice parameter and the rhombohedral angle \(\alpha = 60^\circ\) and 109.47\(^\circ\) for FCC and BCC respectively. The HCP structure is placed in a \(3 \times 3 \times 2\) typical two-atom hexagonal supercell with the basis vectors set as

- \(\mathbf{a}_1 = a \cdot (1, 0, 0)\),
- \(\mathbf{a}_2 = a \cdot (\frac{1}{2}, \frac{1}{2}, 0)\),
- \(\mathbf{a}_3 = a \cdot (0, 0, c/a)\)

with \(a\) and \(c/a\) standing for the lattice parameter and axial ratio respectively as shown in Fig.1(b). The selected atom in the three structures are moved 0.5 Å by a step of 0.05 Å along the \(x\) (for FCC, BCC) or the \(x, y, z\) axes (for HCP) and the potential energies at each step are calculated by the DFT implemented in Vienna Ab initio Simulation Package.\(^\text{45, 49}\) The projector-augmented wave formalism with 3 valence electrons (3s2p\(^3\)) considered are adopted for the pseudopotential and the general gradient approximation of the Perdew-Burke-Ernzerh parametrizations is used for the exchange-correlation functional. The Brillouin zone is sampled by a Γ-centered \(9 \times 9 \times 9\) uniform \(k\)-mesh grid by the Monkhorst-Pack scheme and the cut-off energy of the plane-wave basis is set as 312.4 eV. The obtained potential energy curves of \(U\) are afterwards smoothed by the spline interpolation algorithm and shown in the supplementary materials.

The Gibbs FEs of the FCC, BCC and HCP phases of Al at room temperature are computed according to Eq.\(^\text{55}\) up to 600 GPa and the transition pressures are determined by the differences of the Gibbs FEs as shown in Fig.2(a). It should be pointed out that the value of the axial ratio of the HCP structure may not equal to the ideal value as \(c/a = \sqrt{8}/3\) at high-pressure zone.\(^\text{26}\) and, as a result, four additional HCP structures with axial ratio of \(c/a = 1.61, 1.62, 1.63, 1.64\) are considered in a pressure range from 150 to 600 GPa in order to confirm the most stable HCP structure. The Gibbs FEs of the four structures relative to the ideal one are shown in Fig.2(b)\(^\text{55}\) and it is found that the one with \(c/a = 1.62\) becomes the minimum as pressures increased to the range of 174 ~ 455 GPa, indicating that, instead of the ideal value, the axial ratio of the stable HCP structure would be \(c/a = 1.62\) in the high-pressure range, which coincides well with the value of the axial ratio observed in Refs.\(^\text{36–38}\) and, as a result, about 1.64 observed in Refs.\(^\text{37, 38}\). With the confirmed HCP structure, the structural phase transition of FCC→HCP→BCC are reproduced by DIA that the FCC structure remains to be the stable phase until 194 GPa when the HCP structure with the axial ratio of 1.62 emerges, and the BCC structure finally replaces the HCP to be the stable phase starting from 381 to 600 GPa. As listed in Table.I, the determined two transition pressures by DIA again are almost the same as the results reported in the experiment by Dewaele et al.\(^\text{14}\) and about 13% different from the reported ~ 220 and ~ 320 GPa in the other experiments.\(^\text{36, 38}\)

As a comparison, it would be very interesting to check the difference between the results obtained by DIA and those by the criteria of enthalpy at 0K in order to clarify the contributions of thermal effects to the structural
TABLE I. Transition pressures for crystalline Al at 300K determined by theoretical and experimental works.

<table>
<thead>
<tr>
<th>phase transition</th>
<th>Theoretical Results (GPa)</th>
<th>Experimental Results (GPa)</th>
</tr>
</thead>
<tbody>
<tr>
<td>FCC→HCP</td>
<td>DIA</td>
<td>194</td>
</tr>
<tr>
<td></td>
<td>0K-enthalpy</td>
<td>ab initio</td>
</tr>
<tr>
<td>HCP→BCC</td>
<td>361</td>
<td>378</td>
</tr>
</tbody>
</table>

On the other hand, nevertheless, the exclusion of thermal effects leads to prominently different transition pressures, 171 and 378 GPa, which are consistent with the results from previous computations [33, 35], but about 11% lower and 5% higher than those determined by DIA respectively. Although such a difference is not as large as that predicted in previous works based on phonon model [30, 33], the deficiency of the criterion of enthalpy at 0K is apparently manifested by much more deviations of the transition pressures from all the exiting experimental data as listed in Table I.

With the determined transition pressures, according to Eq. (2), the $P$-$V$ EOS of crystalline Al and the phase diagram at room temperature are obtained as shown in Fig. 3. The EOS by DIA coincides well with those measured in the existing experiments [25, 36, 37, 39], and the obtained atomic volume of the FCC structure at standard condition, $V_0 = 16.845 \text{ Å}^3$/atom, differs about 1.5% from the values of 16.573 $\text{ Å}^3$/atom in Refs. [25, 36] and 16.597 $\text{ Å}^3$/atom in Ref. [39]. The phase boundaries of the three structures are further determined to be located at $V/V_0 = 0.517$ for FCC→HCP and $V/V_0 = 0.426$ for HCP→BCC, and there are two prominent discontinuities of $0.674\%$ and $0.897\%$ volume changes at the transition points respectively, which are very close to the reported volume changes of $-1.0\%$ and $-0.8\%$ in Ref. [39], but far less than the values of $3.2 \pm 0.3\%$ and $2.7 \pm 0.6\%$ observed in the Ref. [37]. Based on the transition pressures and axial ratio of HCP structures at high pressure zone discussed above, the computations by DIA support the results in the experiment conducted by Dewaele et al. [39], and the disagreements with other experiments, according to the careful analysis in Ref. [39], may be due to the usage of uncorrected empirical EOS for the pressure markers or the difficulty in controlling the temperature effects in the ramp compressions by laser.

In conclusion, by applying the DIA to solve the PFs of the three phases of crystalline Al, the derived Gibbs FE is used as the criterion to investigate the structural phase stability under high pressures at room temperature and the obtained equilibrium structures, transition pressures and EOS strictly are in an excellent agreement with the results from the recent experiment by Dewaele et al [39], especially validating that the transition pressure of FCC→HCP is much lower and the one of HCP→BCC is much higher than those reported in other experiments. Furthermore, the comparison with the results obtained by the commonly-used criterion of enthalpy shows that, even at room temperature, the thermal contributions play a nontrivial role in determining the phase stability, especially at high-pressure extreme conditions. The high efficiency and precision of DIA to PF make it possible to implement the FE with $ab\ initio$ computational...
accuracy as the very criterion to study phase behaviors of condensed matters under extreme conditions in the future.

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